







	<h2>SI3430DV-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3430DV-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 1.8A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3430DV-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 65887 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI3430DV-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 100V 1.8A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	65887 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.8A (Ta)
Rds On (Max) @ Id, Vgs	170 mOhm @ 2.4A, 10V
VGS (th) (Max) @ Id	2V @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	6.6nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SI3430DV-T1-GE3 ist neu im Original, Suche SI3430DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3430DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3430DV-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI3433BDV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.3A 6-TSOP</p>	 <p><b>SI3433BDV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.3A 6-TSOP</p>	 <p><b>SI3430DV-T1</b> VISHAY SI3430DV-T1 VISHAY</p>	 <p><b>SI3429EDV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CHAN 20V TSOP6S</p>
 <p><b>SI3430DV-T1-E3</b> Vishay / Siliconix MOSFET N-CH 100V 1.8A 6-TSOP</p>	 <p><b>SI3430DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 100V 1.8A 6-TSOP</p>	 <p><b>SI3429EDV-T1-GE3</b> Vishay / Siliconix MOSFET P-CHAN 20V TSOP6S</p>	 <p><b>SI3433BDV-T1-E3</b> Vishay / Siliconix MOSFET P-CH 20V 4.3A 6-TSOP</p>

### heiße Teile

Mehr

 SI3420DV-T1-GE3	 SI3421DV-T1-GE3	 SI3421DV-T1-GE3	 SI3422DV	 SI3422DV-T1
 SI3422DV-T1-GE3	 SI3424BDV	 SI3424BDV-T1-E3	 SI3424BDV-T1-E3	 SI3424BDV-T1-GE3
 SI3424BDV-T1-GE3	 SI3424CDV	 SI3424CDV-T1-E3	 SI3424CDV-T1-GE3	 SI3424CDV-T1-GE3
 SI3424DV-T1	 SI3424DV-T1-E3	 SI3424DV-T1-E3	 SI3424DV-T1-GE3	 SI3424DV-T1-GE3
 SI3424DV-T1-E3	 SI3425DV	 SI3429EDV-T1-GE3	 SI3429EDV-T1-GE3	 SI3430DV-T1
 SI3430DV-T1-GE3	 SI3433BDV-T1	 SI3433BDV-T1-E3	 SI3433BDV-T1-E3	 SI3433BDV-T1-GE3
 SI3433BDV-T1-GE3	 SI3433CDV-T1-E3	 SI3433CDV-T1-E3	 SI3433CDV-T1-GE3	 SI3433CDV-T1-GE3
 SI3433DN	 SI3433DV-T1	 SI3433DV-T1-E	 SI3433DV-T1-E3	 SI3433DV-T1-GE3
 SI3434DV-T1	 SI3434DV-T1-E3	 SI3434DV-T1-E3	 SI3434DV-T1-GE3	 SI3434DV-T1-GE3
 SI3435DV-T1	 SI3435DV-T1-E3	 SI3435DV-T1-GE3	 SI3437DV-T1-E3	 SI3437DV-T1-E3

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